NSN 5961-01-331-1056

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-331-1056 **Inclosure Material:** Metal **Overall Length:** Between 1.195 inches and 1.205 inches **Overall Height:** 0.220 inches **Overall Width:** Between 0.545 inches and 0.555 inches **End Application:** An/tyq-2 (v) 1 tactical air operations central **Internal Configuration:** Field effect **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 12.00 amperes drain current **Power Rating Per Characteristic:** 269.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No